



# 74VCXH16245

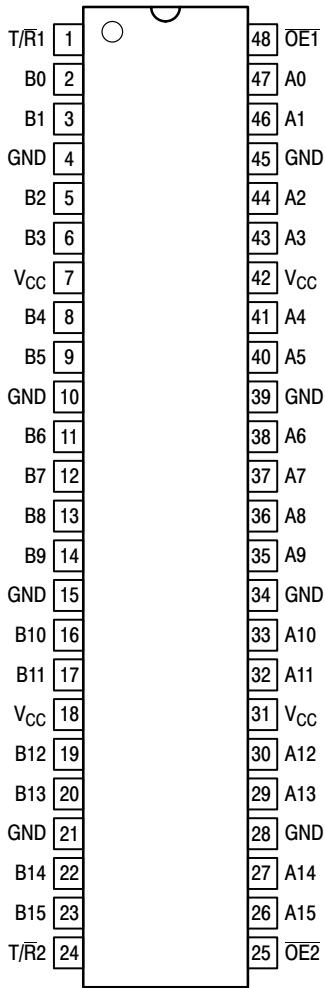


Figure 1. 48-Lead Pinout  
(Top View)

### PIN NAMES

Pins	Function
$\overline{OE}n$	Output Enable Inputs
T/Rn	Transmit/Receive Inputs
A0–A15	Side A Inputs or 3–State Outputs
B0–B15	Side B Inputs or 3–State Outputs

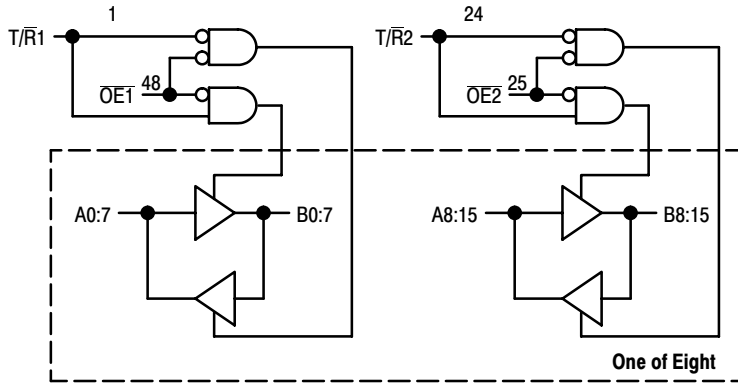


Figure 2. Logic Diagram

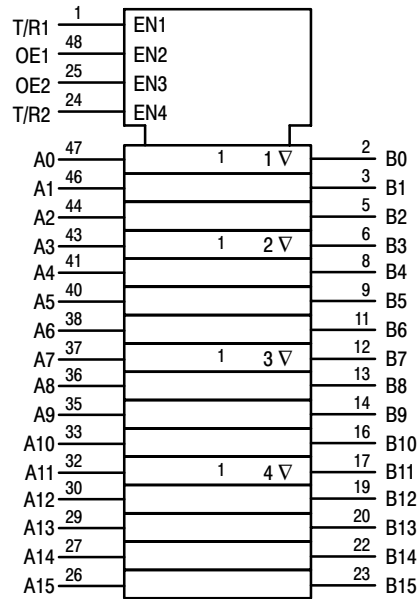


Figure 3. IEC Logic Diagram

Inputs		Outputs	Inputs		Outputs
$\overline{OE}1$	T/R1		$\overline{OE}2$	T/R2	
L	L	Bus B0:7 Data to Bus A0:7	L	L	Bus B8:15 Data to Bus A8:15
L	H	Bus A0:7 Data to Bus B0:7	L	H	Bus A8:15 Data to Bus B8:15
H	X	High Z State on A0:7, B0:7	H	X	High Z State on A8:15, B8:15

H = High Voltage Level; L = Low Voltage Level; X = High or Low Voltage Level and Transitions Are Acceptable

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## ABSOLUTE MAXIMUM RATINGS\*

Symbol	Parameter	Value	Condition	Unit
$V_{CC}$	DC Supply Voltage	-0.5 to +4.6		V
$V_I$	DC Input Voltage	$-0.5 \leq V_I \leq +4.6$		V
$V_O$	DC Output Voltage	$-0.5 \leq V_O \leq +4.6$	Output in 3-State	V
		$-0.5 \leq V_O \leq V_{CC} + 0.5$	Note 1.; Outputs Active	V
$I_{IK}$	DC Input Diode Current	-50	$V_I < \text{GND}$	mA
$I_{OK}$	DC Output Diode Current	-50	$V_O < \text{GND}$	mA
		+50	$V_O > V_{CC}$	mA
$I_O$	DC Output Source/Sink Current	$\pm 50$		mA
$I_{CC}$	DC Supply Current Per Supply Pin	$\pm 100$		mA
$I_{GND}$	DC Ground Current Per Ground Pin	$\pm 100$		mA
$T_{STG}$	Storage Temperature Range	-65 to +150		°C

\* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

1.  $I_O$  absolute maximum rating must be observed.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit	
$V_{CC}$	Supply Voltage	Operating	1.65	3.3	3.6	V
		Data Retention Only	1.2	3.3	3.6	
$V_I$	Input Voltage	-0.3		3.6	V	
$V_O$	Output Voltage	(Active State)	0		$V_{CC}$	V
		(3-State)	0		3.6	
$I_{OH}$	HIGH Level Output Current, $V_{CC} = 3.0 \text{ V} - 3.6 \text{ V}$			-24	mA	
$I_{OL}$	LOW Level Output Current, $V_{CC} = 3.0 \text{ V} - 3.6 \text{ V}$			24	mA	
$I_{OH}$	HIGH Level Output Current, $V_{CC} = 2.3 \text{ V} - 2.7 \text{ V}$			-18	mA	
$I_{OL}$	LOW Level Output Current, $V_{CC} = 2.3 \text{ V} - 2.7 \text{ V}$			18	mA	
$I_{OH}$	HIGH Level Output Current, $V_{CC} = 1.65 - 1.95 \text{ V}$			-6	mA	
$I_{OL}$	LOW Level Output Current, $V_{CC} = 1.65 - 1.95 \text{ V}$			6	mA	
$T_A$	Operating Free-Air Temperature	-40		+85	°C	
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, $V_{IN}$ from 0.8 V to 2.0 V, $V_{CC} = 3.0 \text{ V}$	0		10	ns/V	

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## DC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Condition	T <sub>A</sub> = -40°C to +85°C		Unit
			Min	Max	
V <sub>IH</sub>	HIGH Level Input Voltage (Note 2.)	1.65 V ≤ V <sub>CC</sub> < 2.3 V	0.65 x V <sub>CC</sub>		V
		2.3 V ≤ V <sub>CC</sub> ≤ 2.7 V	1.6		
		2.7 V < V <sub>CC</sub> ≤ 3.6 V	2.0		
V <sub>IL</sub>	LOW Level Input Voltage (Note 2.)	1.65 V ≤ V <sub>CC</sub> < 2.3 V		0.35 x V <sub>CC</sub>	V
		2.3 V ≤ V <sub>CC</sub> ≤ 2.7 V		0.7	
		2.7 V < V <sub>CC</sub> ≤ 3.6 V		0.8	
V <sub>OH</sub>	HIGH Level Output Voltage	1.65 V ≤ V <sub>CC</sub> ≤ 3.6 V; I <sub>OH</sub> = -100μA	V <sub>CC</sub> - 0.2		V
		V <sub>CC</sub> = 1.65 V; I <sub>OH</sub> = -6mA	1.25		
		V <sub>CC</sub> = 2.3 V; I <sub>OH</sub> = -6mA	2.0		
		V <sub>CC</sub> = 2.3 V; I <sub>OH</sub> = -12mA	1.8		
		V <sub>CC</sub> = 2.3 V; I <sub>OH</sub> = -18mA	1.7		
		V <sub>CC</sub> = 2.7 V; I <sub>OH</sub> = -12mA	2.2		
		V <sub>CC</sub> = 3.0 V; I <sub>OH</sub> = -18mA	2.4		
V <sub>OL</sub>	LOW Level Output Voltage	1.65 V ≤ V <sub>CC</sub> ≤ 3.6 V; I <sub>OL</sub> = 100μA		0.2	V
		V <sub>CC</sub> = 1.65 V; I <sub>OL</sub> = 6mA		0.3	
		V <sub>CC</sub> = 2.3 V; I <sub>OL</sub> = 12mA		0.4	
		V <sub>CC</sub> = 2.3 V; I <sub>OL</sub> = 18mA		0.6	
		V <sub>CC</sub> = 2.7 V; I <sub>OL</sub> = 12mA		0.4	
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 18mA		0.4	
		V <sub>CC</sub> = 3.0 V; I <sub>OL</sub> = 24mA		0.55	
I <sub>I</sub>	Input Leakage Current	1.65 V ≤ V <sub>CC</sub> ≤ 3.6 V; 0V ≤ V <sub>I</sub> ≤ 3.6 V		±5.0	μA
I <sub>I(HOLD)</sub>	Minimum Bushold Input Current	V <sub>CC</sub> = 3.0 V, V <sub>IN</sub> = 0.8V	75		μA
		V <sub>CC</sub> = 3.0 V, V <sub>IN</sub> = 2.0V	-75		
		V <sub>CC</sub> = 2.3 V, V <sub>IN</sub> = 0.7V	45		
		V <sub>CC</sub> = 2.3 V, V <sub>IN</sub> = 1.6V	-45		
		V <sub>CC</sub> = 1.65 V, V <sub>IN</sub> = 0.57V	25		
		V <sub>CC</sub> = 1.65 V, V <sub>IN</sub> = 1.07V	-25		
I <sub>I(OD)</sub>	Minimum Bushold Over-Drive Current Needed to Change State	V <sub>CC</sub> = 3.6 V, (Note 3.)	450		μA
		V <sub>CC</sub> = 3.6 V, (Note 4.)	-450		
		V <sub>CC</sub> = 2.7 V, (Note 3.)	300		
		V <sub>CC</sub> = 2.7 V, (Note 4.)	-300		
		V <sub>CC</sub> = 1.95 V, (Note 3.)	200		
		V <sub>CC</sub> = 1.95 V, (Note 4.)	-200		
I <sub>OZ</sub>	3-State Output Current	1.65 V ≤ V <sub>CC</sub> ≤ 3.6 V; 0 V ≤ V <sub>O</sub> ≤ 3.6 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		±10	μA
I <sub>OFF</sub>	Power-Off Leakage Current	V <sub>CC</sub> = 0 V; V <sub>I</sub> or V <sub>O</sub> = 3.6 V		10	μA
I <sub>CC</sub>	Quiescent Supply Current (Note 5.)	1.65 V ≤ V <sub>CC</sub> ≤ 3.6 V; V <sub>I</sub> = GND or V <sub>CC</sub>		20	μA
		1.65 V ≤ V <sub>CC</sub> ≤ 3.6 V; 3.6 V ≤ V <sub>I</sub> , V <sub>O</sub> ≤ 3.6 V		±20	μA
ΔI <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	2.7 V < V <sub>CC</sub> ≤ 3.6 V; V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V		750	μA

2. These values of V<sub>I</sub> are used to test DC electrical characteristics only.

3. An external driver must source at least the specified current to switch from LOW-to-HIGH.

4. An external driver must source at least the specified current to switch from HIGH-to-LOW.

5. Outputs disabled or 3-state only.

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## AC CHARACTERISTICS (Note 6.; $t_R = t_F = 2.0\text{ns}$ ; $C_L = 30\text{pF}$ ; $R_L = 500\Omega$ )

Symbol	Parameter	Waveform	Limits						Unit
			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$						
			$V_{CC} = 3.0\text{ V to } 3.6\text{ V}$		$V_{CC} = 2.3\text{ V to } 2.7\text{ V}$		$V_{CC} = 1.65\text{ to } 1.95\text{ V}$		
			Min	Max	Min	Max	Min	Max	
$t_{PLH}$ $t_{PHL}$	Propagation Delay Input to Output	1	0.8 0.8	2.5 2.5	1.0 1.0	3.0 3.0	1.5 1.5	6.0 6.0	ns
$t_{PZH}$ $t_{PZL}$	Output Enable Time to High and Low Level	2	0.8 0.8	3.8 3.8	1.0 1.0	4.9 4.9	1.5 1.5	9.3 9.3	ns
$t_{PHZ}$ $t_{PLZ}$	Output Disable Time From High and Low Level	2	0.8 0.8	3.7 3.7	1.0 1.0	4.2 4.2	1.5 1.5	7.6 7.6	ns
$t_{OSHL}$ $t_{OSLH}$	Output-to-Output Skew (Note 7.)			0.5 0.5		0.5 0.5		0.75 0.75	ns

6. For  $C_L = 50\text{pF}$ , add approximately 300ps to the AC maximum specification.

7. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW ( $t_{OSHL}$ ) or LOW-to-HIGH ( $t_{OSLH}$ ); parameter guaranteed by design.

## DYNAMIC SWITCHING CHARACTERISTICS

Symbol	Characteristic	Condition	$T_A = +25^\circ\text{C}$	Unit
			Typ	
$V_{OLP}$	Dynamic LOW Peak Voltage (Note 8.)	$V_{CC} = 1.8\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	0.25	V
		$V_{CC} = 2.5\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	0.6	
		$V_{CC} = 3.3\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	0.8	
$V_{OLV}$	Dynamic LOW Valley Voltage (Note 8.)	$V_{CC} = 1.8\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	-0.25	V
		$V_{CC} = 2.5\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	-0.6	
		$V_{CC} = 3.3\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	-0.8	
$V_{OHV}$	Dynamic HIGH Valley Voltage (Note 9.)	$V_{CC} = 1.8\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	1.5	V
		$V_{CC} = 2.5\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	1.9	
		$V_{CC} = 3.3\text{ V}, C_L = 30\text{pF}, V_{IH} = V_{CC}, V_{IL} = 0\text{ V}$	2.2	

8. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

9. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the HIGH state.

## CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
$C_{IN}$	Input Capacitance	Note 10.	6	pF
$C_{OUT}$	Output Capacitance	Note 10.	7	pF
$C_{PD}$	Power Dissipation Capacitance	Note 10., 10MHz	20	pF

10.  $V_{CC} = 1.8, 2.5$  or  $3.3\text{ V}$ ;  $V_I = 0\text{ V}$  or  $V_{CC}$ .

## AC CHARACTERISTICS ( $t_R = t_F = 2.0\text{ns}$ ; $C_L = 50\text{pF}$ ; $R_L = 500\Omega$ )

Symbol	Parameter	Waveform	Limits				Unit
			$T_A = -40^\circ\text{C to } +85^\circ\text{C}$				
			$V_{CC} = 3.0\text{ V to } 3.6\text{ V}$		$V_{CC} = 2.7\text{ V}$		
			Min	Max	Min	Max	
$t_{PLH}$ $t_{PHL}$	Propagation Delay Input to Output	3	1.0 1.0	3.0 3.0		3.6 3.6	ns
$t_{PZH}$ $t_{PZL}$	Output Enable Time to High and Low Level	4	1.0 1.0	4.4 4.4		5.4 5.4	ns
$t_{PHZ}$ $t_{PLZ}$	Output Disable Time From High and Low Level	4	1.0 1.0	4.1 4.1		4.6 4.6	ns
$t_{OSHL}$ $t_{OSLH}$	Output-to-Output Skew (Note 11.)			0.5 0.5		0.5 0.5	ns

11. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW ( $t_{OSHL}$ ) or LOW-to-HIGH ( $t_{OSLH}$ ); parameter guaranteed by design.

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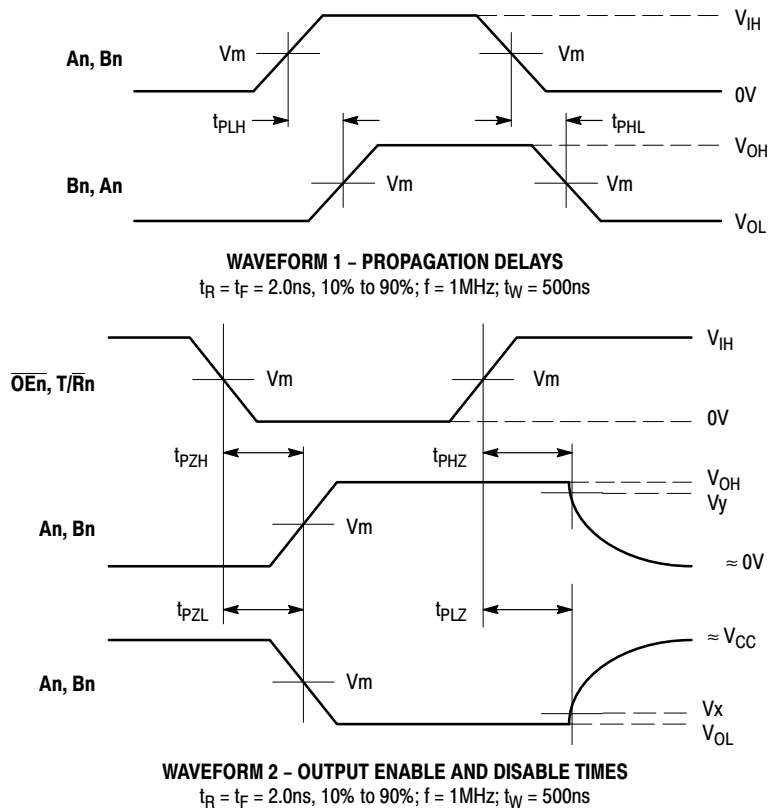
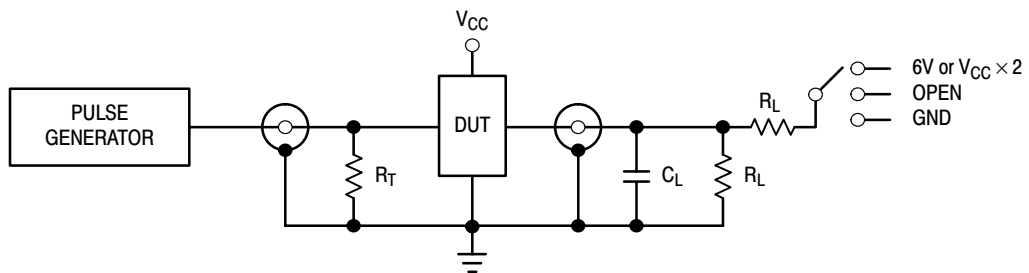


Figure 4. AC Waveforms

Symbol	V <sub>CC</sub>		
	3.3 V ±0.3 V	2.5V ±0.2 V	1.8 V ±0.15 V
V <sub>IH</sub>	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>m</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
V <sub>x</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V
V <sub>y</sub>	V <sub>OH</sub> - 0.3 V	V <sub>OH</sub> - 0.15 V	V <sub>OH</sub> - 0.15 V



TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6 V at V <sub>CC</sub> = 3.3 ±0.3 V; V <sub>CC</sub> × 2 at V <sub>CC</sub> = 2.5 ±0.2 V; 1.8 V ±0.15 V
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND

C<sub>L</sub> = 30pF or equivalent (Includes jig and probe capacitance)  
R<sub>L</sub> = 500Ω or equivalent  
R<sub>T</sub> = Z<sub>OUT</sub> of pulse generator (typically 50Ω)

Figure 5. Test Circuit

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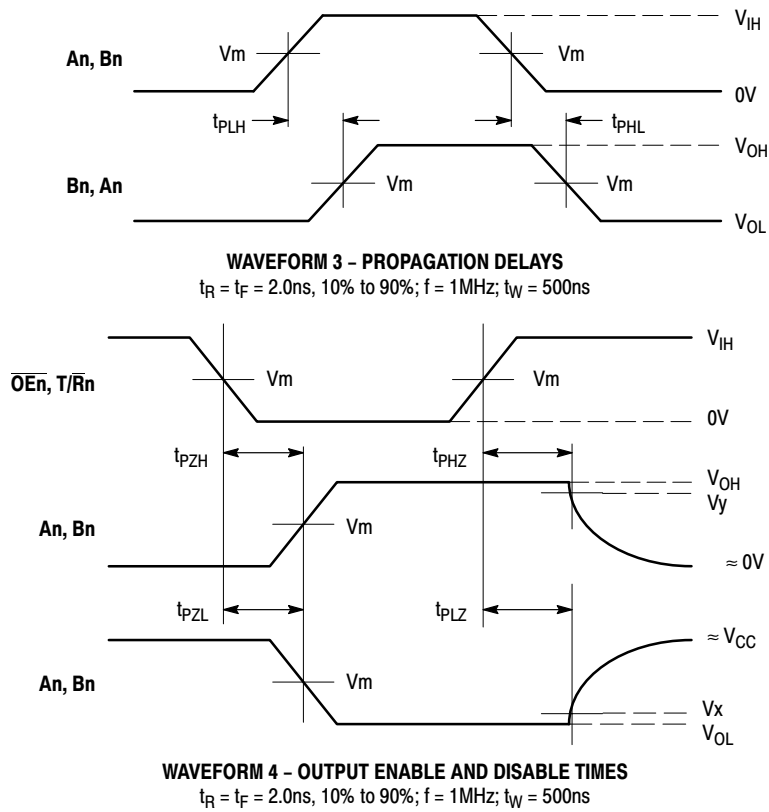
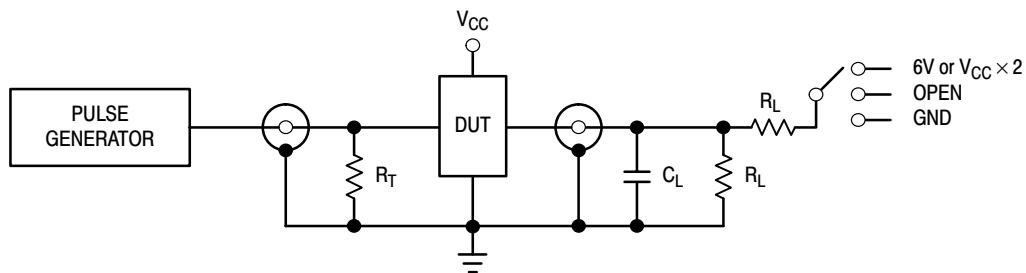


Figure 6. AC Waveforms

Symbol	V <sub>CC</sub>	
	3.3V ±0.3 V	2.7 V
V <sub>IH</sub>	2.7 V	2.7 V
V <sub>m</sub>	1.5 V	1.5 V
V <sub>x</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.3 V
V <sub>y</sub>	V <sub>OH</sub> - 0.3 V	V <sub>OH</sub> - 0.3 V



TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6 V at V <sub>CC</sub> = 3.3 ±0.3V; V <sub>CC</sub> × 2 at V <sub>CC</sub> = 2.5 ±0.2 V; 1.8 ±0.15 V
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND

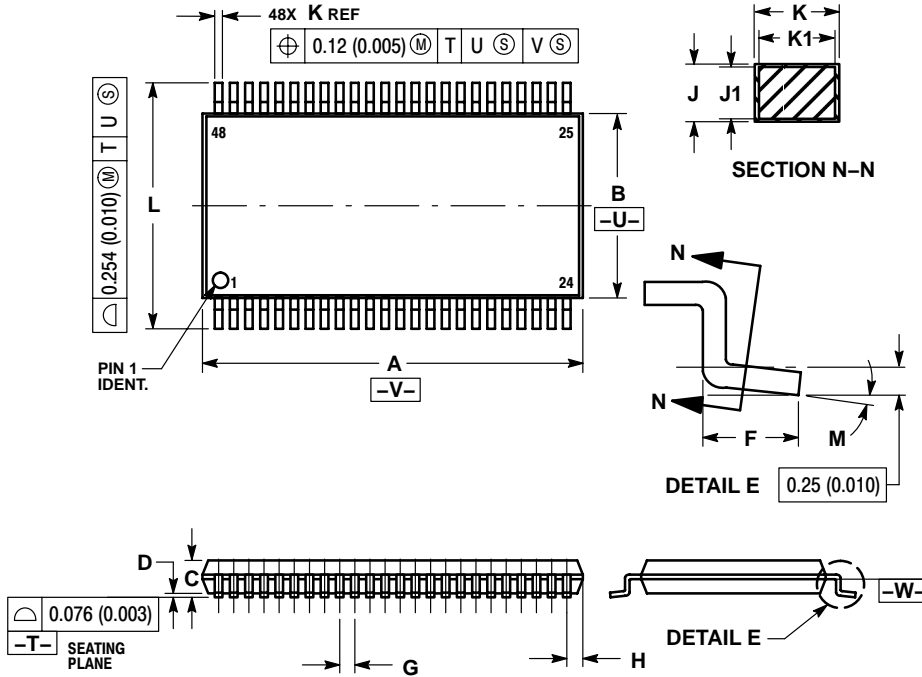
C<sub>L</sub> = 50pF or equivalent (Includes jig and probe capacitance)  
R<sub>L</sub> = 500Ω or equivalent  
R<sub>T</sub> = Z<sub>OUT</sub> of pulse generator (typically 50Ω)

Figure 7. Test Circuit

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## PACKAGE DIMENSIONS

TSSOP  
DT SUFFIX  
CASE 1201-01  
ISSUE A



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	12.40	12.60	0.488	0.496
B	6.00	6.20	0.236	0.244
C	---	1.10	---	0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.50 BSC		0.0197 BSC	
H	0.37	---	0.015	---
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.17	0.27	0.007	0.011
K1	0.17	0.23	0.007	0.009
L	7.95	8.25	0.313	0.325
M	0°	8°	0°	8°

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